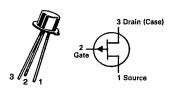
CASE 22-03, STYLE 12 TO-18 (TO-206AA)



JFETs GENERAL PURPOSE

P-CHANNEL --- DEPLETION

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Drain-Source Voltage	VDS	30	Vdc	
Drain-Gate Voltage	V _{DG}	30	Vdc	
Gate-Source Voltage	VGS	30	Vdc	
Drain Current	ΙD	50	mA	
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	300 1.7	mW mW/°C	
Storage Temperature Range	T _{stg}	-60 to +200	°C	

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Gate-Source Breakdown Voltage (I _G = 1.0 μA)		V(BR)GSS	30	_	Vdc
Gate Reverse Current (VGS = 5.0 V)		IGSS	1	10	пА
Gate Source Cutoff Voltage (VDS = -5.0 V, ID = -1.0 μ A)		VGS(off)	1	1.7	Vdc
ON CHARACTERISTICS					
Zero-Gate-Voltage Drain Current (V _{DS} = -5.0 V)	2N2843 2N2844	loss*	-200 -440	-1000 -2200	μΑ
SMALL-SIGNAL CHARACTERISTICS					
Forward Transfer Admittance (V _{DS} = -5.0 V, f = 1.0 kHz)	2N2843 2N2844	Yfs *	540 1400	=	μmhos
Input Capacitance $(V_{DS} = -5.0 \text{ V}, V_{GS} = 1.0 \text{ V}, f = 140 \text{ kHz})$	2N2843 2N2844	Ciss	=	17 30	pF
FUNCTIONAL CHARACTERISTICS					
Noise Figure (V _{DS} = -5.0 V, f = 1.0 kHz, R _G = 1.0 meg)		NF	_	3.0	dB

^{*}Pulse Width ≤ 630 ms, Duty Cycle = 10%.